

MAPC-A1500

Rev. V5

Features

- MACOM PURE CARBIDE™ Amplifier Series
- Suitable for Linear & Saturated Applications
- Pulsed Operation: 2600 W Output Power @ 65 V 2000 W Output Power @ 50 V
- Internally Pre-Matched
- 260°C Reflow Compatible
- 65 V Operation
- 100% RF Tested
- RoHS* Compliant
- Compatible with MACOM Power Management Bias Controller/Sequencer MABC-11040

Applications

Avionics, IFF Transponders.

Description

The MAPC-A1500 is a high power GaN on Silicon Carbide HEMT D-mode amplifier suitable for 960 - 1215 MHz frequency operation. The device supports pulsed operation with output power levels of 2600 W (64.1 dBm) at 65 V and 2000 W (63.0 dBm) at 50 V and in an air cavity ceramic package.

Typical Performance:

Measured under load-pull at 2.5 dB Compression, 100 µs pulse width, 1% duty cycle.

Frequency (MHz)	Output Power ¹ (dBm)	Gain² (dB)	η _D ² (%)
960	65.4	20.8	76.1
1030	65.2	20.4	73.1
1090	65.1	20.4	73.1
1215	64.9	18.8	71.0

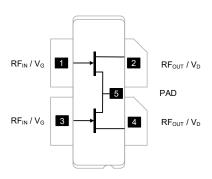
$V_{DS} = 50 \text{ V}, I_{DQ} = 1300 \text{ mA}, T_{C} = 25^{\circ}\text{C}$

Frequency (MHz)	Output Power ¹ (dBm)	Gain² (dB)	η _D ² (%)
960	64.1	19.9	71.2
1030	63.8	19.6	70.4
1090	63.7	19.1	70.7
1215	63.7	18.4	71.3

^{1.} Load impedance tuned for maximum output power. Power is twice single side performance.



Functional Schematic



Pin Configuration

Pin#	Pin Name	Function
1, 3	RF _{IN} / V _G	RF Input / Gate
2, 4	RF _{OUT} / V _D	RF Output / Drain
5	Flange ³	Ground / Source

The flange on the package bottom must be connected to RF, DC and thermal ground.

Ordering Information

Part Number	Package
MAPC-A1500-AS000	Bulk Quantity: Earless
MAPC-A1500-ASTR1	Tape and Reel: Earless
MAPC-A1500-ASSB1	Sample Board: Earless
MAPC-A1500-AB000	Bulk Quantity: Boltdown
MAPC-A1500-ABTR1	Tape and Reel: Boltdown
MAPC-A1500-ABSB1	Sample Board: Boltdown

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

^{2.} Load impedance tuned for maximum drain efficiency.



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RF Electrical Characteristics: $T_C = 25^{\circ}C$, $V_{DS} = 65$ V, $I_{DQ} = 1300$ mA Note: Performance in MACOM 1030-1090 MHz Evaluation Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed ⁴ , 1.06 GHz	Gss	-	18.3	-	dB
Saturated Output Power	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	P _{SAT}	-	64.2	-	dBm
Power Gain	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	G _{SAT}	-	18.5	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	η _{SAT}	-	66.2	-	%
Gain Variation (-40°C to +85°C)	Pulsed ⁴ , 1.06 GHz	ΔG	-	0.018	-	dB/°C
Power Variation (-40°C to +85°C)	Pulsed ⁴ , 1.06 GHz	ΔP2.5dB	-	0.005	-	dB/°C
Power Gain	Pulsed ⁴ , 1.06 GHz, P _{OUT} = 64.1 dBm	G _P	-	18.9	-	dB
Drain Efficiency	Pulsed ⁴ , 1.06 GHz, P _{OUT} = 64.1 dBm	η	-	65.0	-	%
Input Return Loss	Pulsed ⁴ , 1.06 GHz, P _{OUT} = 64.1 dBm	IRL	-	-10	-	dB
Ruggedness: Output Mismatch	All phase angles	Ψ VSWR = 7:1, No Damage		age		

RF Electrical Characteristics: T_C = 25°C, V_{DS} = 50 V, I_{DQ} = 1300 mA Note: Performance in MACOM 1030-1090 MHz Evaluation Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed ⁴ , 1.06 GHz	Gss	-	16.8	-	dB
Saturated Output Power	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	P _{SAT}	-	63.1	-	dBm
Power Gain	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	G _{SAT}	-	16.9	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	η_{SAT}	-	58	-	%
Gain Variation (-40°C to +85°C)	Pulsed ⁴ , 1.06 GHz	ΔG	-	0.015	-	dB/°C
Power Variation (-40°C to +85°C)	Pulsed ⁴ , 1.06 GHz	ΔP2.5dB	-	0.005	-	dB/°C
Power Gain	Pulsed ⁴ , 1.06 GHz, P _{OUT} = 63.0 dBm	G₽	-	17.5	-	dB
Drain Efficiency	Pulsed ⁴ , 1.06 GHz, P _{OUT} = 63.0 dBm	η	-	57.5	-	%
Input Return Loss	Pulsed ⁴ , 1.06 GHz, P _{OUT} = 63.0 dBm	IRL	-	-10	-	dB
Ruggedness: Output Mismatch	All phase angles	Ψ	Ψ VSWR = 7:1, No Damage		age	

^{4.} Pulse Details: 100 μs pulse width, 1% duty cycle.



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RF Electrical Specifications: T_A = 25°C, V_{DS} = 65 V, I_{DQ} = 650 mA Note: Performance in MACOM 1030-1090 MHz Production Test Fixture, 50 Ω system

Parameter	Test Conditions		Min.	Тур.	Max.	Units
Power Gain	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	G _{SAT}	17.5	18.5	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	η _{SAT}	61.6	66.2	-	%
Saturated Output Power	Pulsed ⁴ , 1.06 GHz, 2.5 dB Gain Compression	P _{SAT}	63	64.2	-	dBm

DC Electrical Characteristics T_A = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	V _{GS} = -8 V, V _{DS} = 130 V	I _{DLK}	-	-	266	mA
Gate-Source Leakage Current	$V_{GS} = -8 \text{ V}, V_{DS} = 0 \text{ V}$	I_{GLK}	-	-	266	mA
Gate Threshold Voltage	V _{DS} = 50 V, I _D = 266 mA	V _T	-3.6	-3.1	-	V
Gate Quiescent Voltage	V _{DS} = 50 V, I _D = 1300 mA	V_{GSQ}	-	-2.85	-	V
On Resistance	V _{GS} = 2 V, I _D = 2000 mA	R _{ON}	-	0.013	-	Ω
Maximum Drain Current	V _{DS} = 7 V pulsed, pulse width 300 μs	I _{D, MAX}	-	253	-	Α



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Absolute Maximum Ratings 5,6,7,8,9

Parameter	Absolute Maximum			
Drain Source Voltage, V _{DS}	130 V			
Gate Source Voltage, V _{GS}	-10 to 3 V			
Gate Current, I _G	266 mA			
Storage Temperature Range	-65°C to +150°C			
Case Operating Temperature Range	-40°C to +85°C			
Channel Operating Temperature Range, T _{CH}	-40°C to +225°C			
Absolute Maximum Channel Temperature	+250°C			

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation above maximum operating conditions.

- Operating at drain source voltage $V_{DS} < 55 \text{ V}$ will ensure MTTF > 2 x 10⁶ hours.

 Operating at nominal conditions with $T_{CH} \le 200^{\circ}\text{C}$ will ensure MTTF > 2 x 10⁶ hours.

 MTTF may be estimated by the expression MTTF (hours) = A $e^{\frac{[B+C/(T+273)]}{2}}$ where T is the channel temperature in degrees Celsius, A = 1, B = -38.215, and C = 26,343.

Thermal Characteristics¹⁰

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis (Pulsed: 100µs, 10%)	$V_{DS} = 65 \text{ V},$ $T_{C} = 85^{\circ}\text{C}, T_{CH} = 225^{\circ}\text{C}$	$R_{\theta}(FEA)$	0.080	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V _{DS} = 65 V, T _C = 85°C, T _{CH} = 225°C	$R_{\theta}(IR)$	0.074	°C/W

^{10.} Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.



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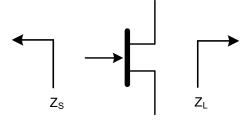
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65 V Pulsed¹³ Load-Pull Performance - Per Side Reference Plane at Device Leads

		Maximum Output Power							
			V _{DS} = 65 V, I _{DQ} = 650 mA, T _C = 25°C, P2.5dB						
Frequency (MHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)		
960	1.1 - j2.0	0.73 - j0.55	19.6	62.4	1740	65.8	32		
1030	2.3 - j1.8	0.68 - j0.61	19.0	62.2	1660	62.5	-3		
1090	2.6 - j0.8	0.64 - j0.62	18.7	62.1	1620	62.2	-32		
1215	1.3 + j0.1	0.62 - j0.73	18.2	61.9	1550	63.7	-81		

		Maximum Drain Efficiency							
			V_{DS} = 65 V, I_{DQ} = 650 mA, T_{C} = 25°C, P2.5dB						
Frequency (MHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)		
960	1.1 - j2.2	0.85 + j0.24	20.8	60.0	1000	76.1	14		
1030	2.6 - j1.5	0.87 + j0.08	20.4	60.0	1000	73.1	-30		
1090	2.5 - j0.1	0.86 + j0.0	20.4	59.5	890	73.1	-69		
1215	1.0 + j0.0	0.77 - j0.12	18.8	59.5	890	71.0	-106		

Impedance Reference



Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.

- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.
- 13. Pulse Details: 15 µs pulse width, 1% duty cycle

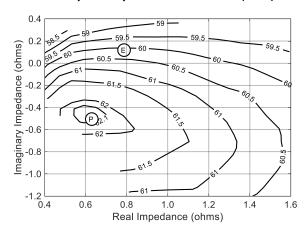


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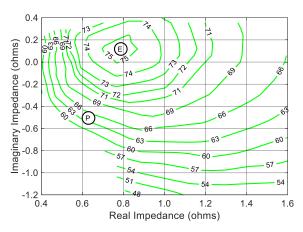
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65 V Pulsed¹³ Load-Pull Performance 1090 MHz - Per Side

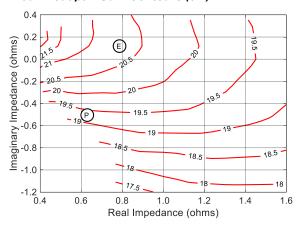
P2.5dB Loadpull Output Power Contours (dBm)



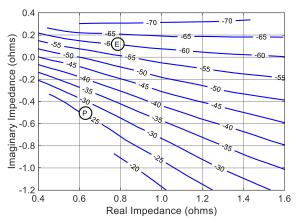
P2.5dB Loadpull Drain Efficiency Contours (%)



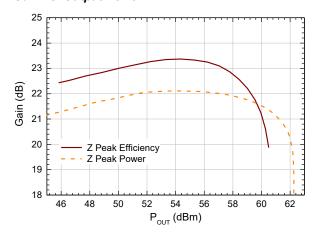
P2.5dB Loadpull Gain Contours (dB)



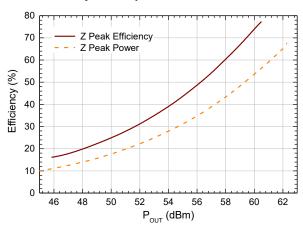
P2.5dB Loadpull AM/PM Contours (°)



Gain vs. Output Power



Drain Efficiency vs. Output Power





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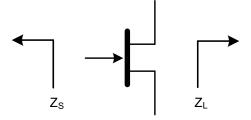
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50 V Pulsed¹³ Load-Pull Performance - Per Side Reference Plane at Device Leads

		Maximum Output Power V _{DS} = 50 V, I _{DQ} = 650 mA, T _C = 25°C, P2.5dB						
Frequency (MHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)	
960	1.2 - j2.2	0.55 - j0.54	19.1	61.1	1290	62.6	35	
1030	2.6 - j1.2	0.54 - j0.81	18.4	60.8	1200	60.8	0	
1090	2.5 + j0.3	0.49 - j0.80	18.4	60.7	1175	60.8	-32	
1215	1.1 - j0.1	0.47 - j0.93	17.7	60.7	1175	59.7	-78	

		Maximum Drain Efficiency $V_{DS} = 50 \text{ V, } I_{DQ} = 650 \text{ mA, } T_{C} = 25^{\circ}\text{C, } P2.5\text{dB}$					
Frequency (MHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)
960	1.2 - j2.2	0.91 + j0.07	19.9	58.5	710	71.2	7
1030	2.6 - j1.2	0.78 - j0.16	19.6	58.5	710	70.4	-36
1090	2.5 + j0.3	0.77 - j0.23	19.1	58.4	690	70.7	-69
1215	1.1 - j0.1	0.68 - j0.38	18.4	58.4	690	71.3	-106

Impedance Reference



Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.

 Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.

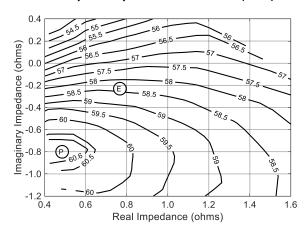


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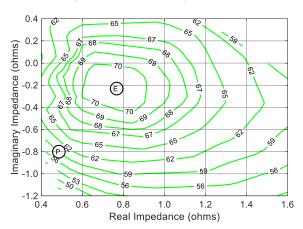
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50 V Pulsed¹³ Load-Pull Performance 1090 MHz - Per Side

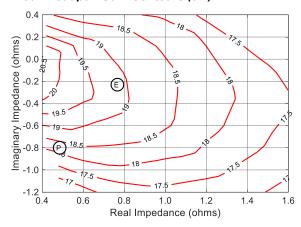
P2.5dB Loadpull Output Power Contours (dBm)



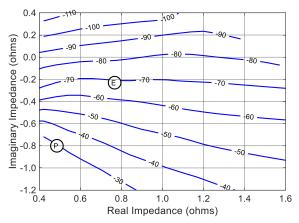
P2.5dB Loadpull Drain Efficiency Contours (%)



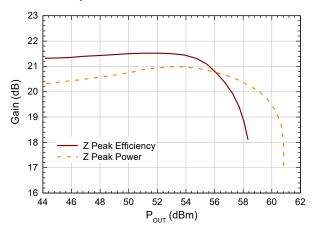
P2.5dB Loadpull Gain Contours (dB)



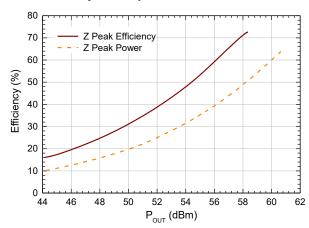
P2.5dB Loadpull AM/PM Contours (°)



Gain vs. Output Power



Drain Efficiency vs. Output Power





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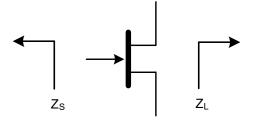
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28 V Pulsed¹⁴ Load-Pull Performance - Per Side Reference Plane at Device Leads

		Maximum Output Power $V_{DS} = 28 \text{ V}, I_{DQ} = 650 \text{ mA}, T_{C} = 25^{\circ}\text{C}, P2.5 \text{dB}$						
Frequency (MHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	Р _{оит} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)	
960	0.50 - j1.5	0.33 - j0.55	16.1	57.4	554	57.8	-0.2	
1030	1.1 - j1.8	0.28 - j0.61	16.4	57.8	607	58.6	-2.6	
1090	1.6 + j1.9	0.27 - j0.65	16.0	57.5	567	57.3	-5.0	
1215	2.0 - j0.5	0.28 - j0.75	15.6	57.4	550	60.6	-7.8	

		Maximum Drain Efficiency $V_{DS} = 28 \text{ V, } I_{DQ} = 650 \text{ mA, } T_{C} = 25^{\circ}\text{C, } P2.5 \text{dB}$						
Frequency (MHz)	Z _{source} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)	
960	0.50 - j1.5	0.62 - j0.20	17.2	54.8	301	68.3	-7.3	
1030	1.1 - j1.8	0.60 - j0.17	16.9	54.5	280	70.8	-12.8	
1090	1.6 + j1.9	0.54 - j0.29	16.7	54.3	268	69.3	-21.3	
1215	2.0 - j0.5	0.50 - j0.36	16.0	54.5	282	71.6	-10.7	

Impedance Reference



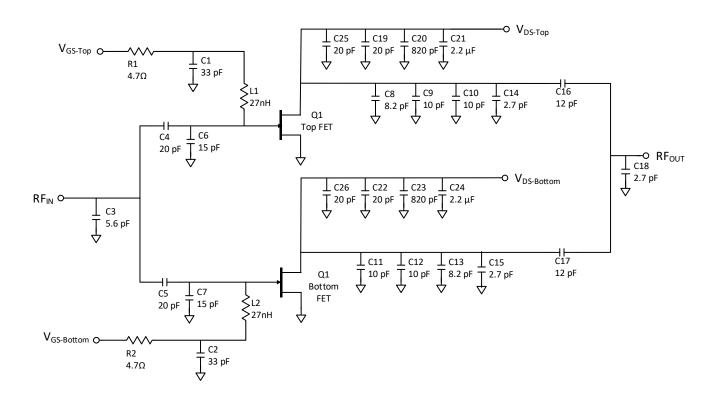
- Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.
- Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.
- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.
 14. Pulse Details: 50 µs pulse width, 1% duty cycle.



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Evaluation Test Fixture and Recommended Tuning Solution 1.03 - 1.09 GHz



Description

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

Bias Sequencing* Turning the device ON

- 1. Set V_{GS} to pinch-off (V_P).
- 2. Turn on V_{DS} to nominal voltage (65 V).
- 3. Increase V_{GS} until I_{DS} current is reached.
- 4. Apply RF power to desired level.

Turning the device OFF

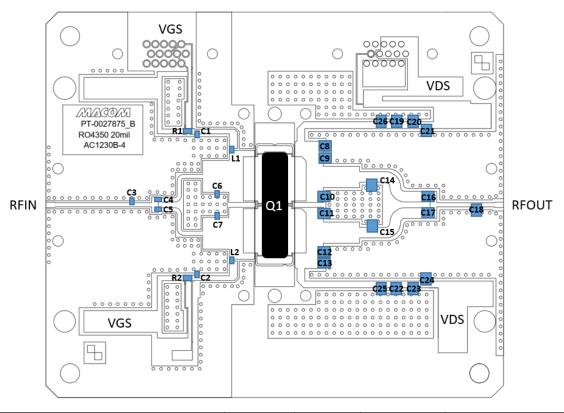
- 1. Turn the RF power OFF.
- 2. Decrease V_{GS} down to V_P pinch-off.
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS}.

^{*} For an integrated power management solution please contact MACOM support regarding the MABC-11040.



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Evaluation Test Fixture and Recommended Tuning Solution 1.03 - 1.09 GHz



Reference Designator	Value	Tolerance	Manufacturer	Part Number		
C1, C2	33 pF	± 5 %	Murata	GQM2195C2E330JB12		
C3	5.6 pF	± 0.1 pF	Murata	GQM2195C2E5R6BB12		
C4, C5	20 pF	± 5 %	Murata	GQM2195C2E200JB12		
C6, C7	15 pF	± 5 %	Murata	GQM2195C2E150JB12		
C8, C13	8.2 pF	± 5 %	Murata	GQM22M5C2H8R2JB01		
C9 - C12	10 pF	± 5 %	Murata	GQM22M5C2H100JB01		
C14, C15, C18	2.7 pF	± 0.1 pF	Murata	GQM22M5C2H2R7BB01		
C16, C17	12 pF	± 5 %	Murata	GQM22M5C2H120JB01		
C19, C22, C25, C26	20 pF	± 5 %	Murata	GQM22M5C2H200JB01		
C20, C23	820 pF	± 5 %	ATC	800B821JT500XT		
C21, C24	2.2 µF	± 10 %	Murata	KRM55TR72E225MH01L		
L1, L2	27 nH	± 5 %	CoilCraft	1008CS-270XJL		
R1, R2	4.7 Ω	± 1 %	Yageo	RT0805FRE074R7L		
Q1	MACO	M GaN Powe	r Amplifier	MAPC-A1500		
PCB		RO4350, 20 mil, 1 oz. Cu, Au Finish				

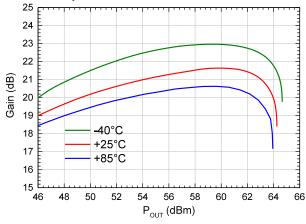


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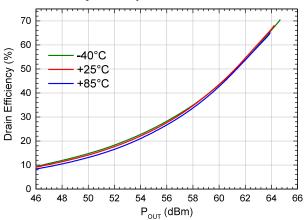
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Typical Performance Curves as Measured in the 1.03 - 1.09 GHz Evaluation Test Fixture: Pulsed⁴ 1.06 GHz, V_{DS} = 65 V, I_{DQ} = 1300 mA, T_{C} = 25°C (Unless Otherwise Noted)

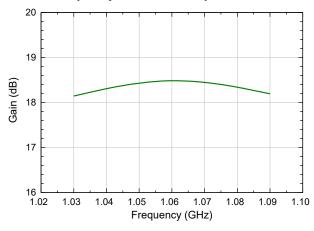
Gain vs. Output Power



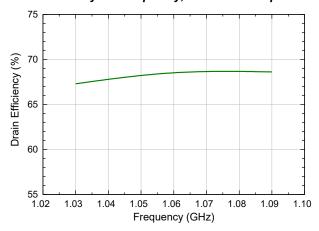
Drain Efficiency vs. Output Power



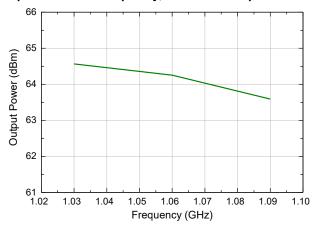
Gain vs. Frequency, 3dB Gain Compression



Drain Efficiency vs. Frequency, 3dB Gain Compression



Output Power vs. Frequency, 3dB Gain Compression



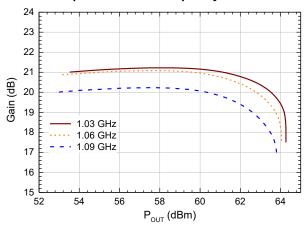


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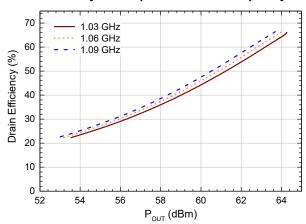
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Typical Performance Curves as Measured in the 1.03 - 1.09 GHz Evaluation Test Fixture: Pulsed⁴ 1.06 GHz, V_{DS} = 65 V, I_{DQ} = 1300 mA, T_{C} = 25°C (Unless Otherwise Noted)

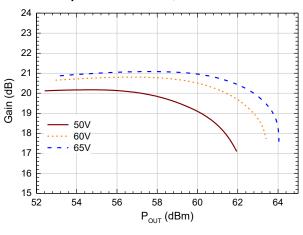
Gain vs. Output Power and Frequency



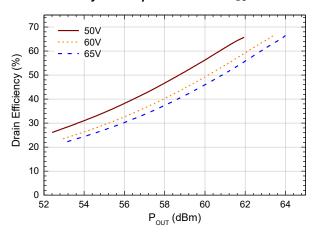
Drain Efficiency vs. Output Power and Frequency



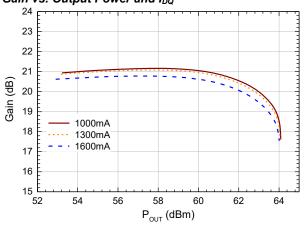
Gain vs. Output Power and V_{DS}



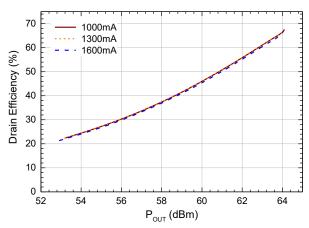
Drain Efficiency vs. Output Power and V_{DS}



Gain vs. Output Power and IDQ



Drain Efficiency vs. Output Power and IDQ

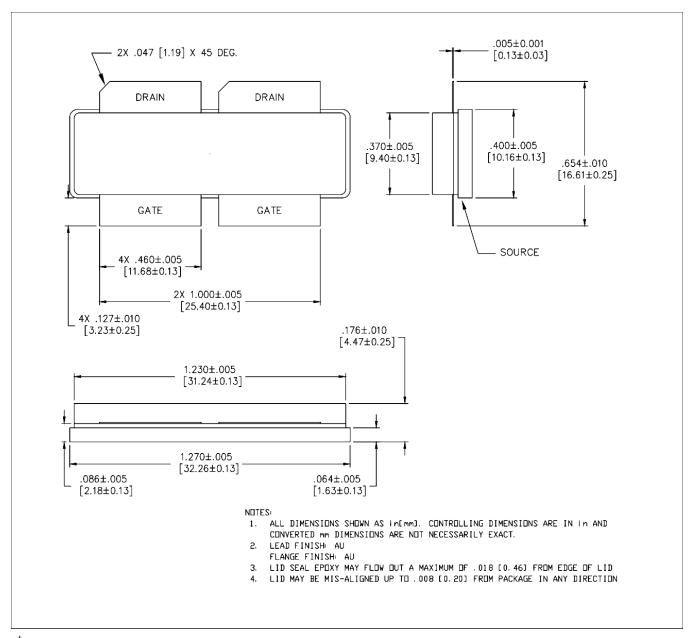




MAPC-A1500

Rev. V5

Lead-Free AC-1230S-4 Package Dimensions[†]



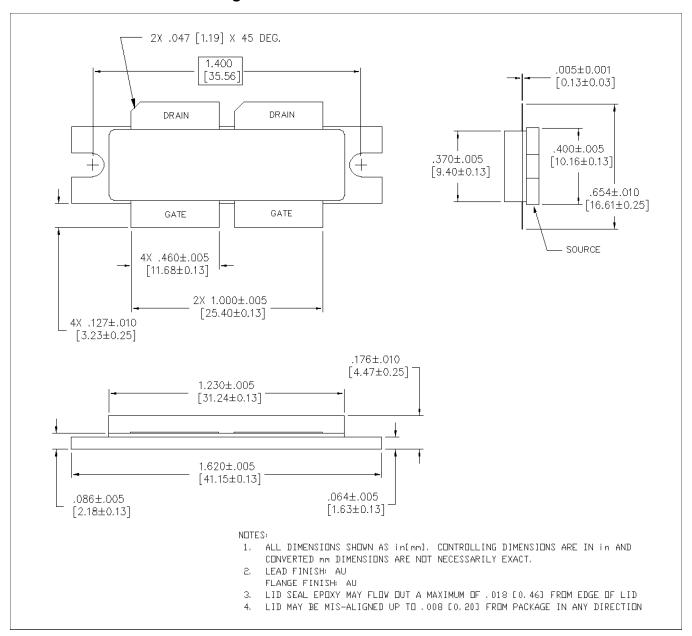
[†] Reference Application Note AN0004363 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.



MAPC-A1500

Rev. V5

Lead-Free AC-1230B-4 Package Dimensions[†]



[†] Reference Application Note AN0004363 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.

GaN Amplifier 65 V, 2600 W 960 - 1215 MHz



MACOM PURE CARBIDE

MAPC-A1500

Rev. V5

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